## MMBZxxVxL, SZMMBZxxVxL Series

## Zener Diodes, 40 Watt Peak Power

## SOT-23 Dual Common Cathode Zeners

These dual monolithic silicon zener diodes are designed for applications requiring protection capability. They are intended for use in voltage and ESD sensitive equipment such as computers, printers, business machines, communication systems, medical equipment and other applications. Their dual junction common cathode design protects two separate lines using only one package. These devices are ideal for situations where board space is at a premium.

## Specification Features:

- SOT-23 Package Allows Either Two Separate Unidirectional Configurations or a Single Bidirectional Configuration
- Standard Zener Breakdown Voltage Range - $15 \mathrm{~V}, 27 \mathrm{~V}, 39 \mathrm{~V}$
- Peak Power - 40 W @ 1.0 ms (Bidirectional), per Figure 5 Waveform
- ESD Rating of Class 3B (exceeding 16 kV ) per the Human Body Model
- ESD Rating of IEC61000-4-2 Level 4, $\pm 30 \mathrm{kV}$ Contact Discharge
- Low Leakage < 100 nA
- Flammability Rating: UL 94 V-O
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These are $\mathrm{Pb}-$ Free Devices


## Mechanical Characteristics:

CASE: Void-free, transfer-molded, thermosetting plastic case
FINISH: Corrosion resistant finish, easily solderable
MAXIMUM CASE TEMPERATURE FOR SOLDERING PURPOSES:
$260^{\circ} \mathrm{C}$ for 10 Seconds

ON Semiconductor ${ }^{\circledR}$
www.onsemi.com


SOT-23
CASE 318
STYLE 9


MARKING DIAGRAM


$$
\begin{aligned}
& \text { XXX }=15 \mathrm{D}, 27 \mathrm{C} \text { or } 39 \mathrm{C} \\
& \mathrm{M} \quad=\text { Date Code } \\
& \text { - } \quad=\text { Pb-Free Package }
\end{aligned}
$$

(Note: Microdot may be in either location)

ORDERING INFORMATION

| Device | Package | Shipping ${ }^{\dagger}$ |
| :--- | :---: | :---: |
| MMBZ15VDLT1G, <br> SZMMBZ15VDLT1G | SOT-23 <br> (Pb-Free) | $3,000 /$ <br> Tape \& Reel |
| MMBZ15VDLT3G, <br> SZMMBZ15VDLT3G | SOT-23 <br> (Pb-Free) | $10,000 /$ <br> Tape \& Reel |
| MMBZxxVCLT1G, <br> SZMMBZxxVCLT1G | SOT-23 <br> (Pb-Free) | $3,000 /$ <br> Tape \& Reel |
| MMBZxxVCLT3G, <br> SZMMBZxxVCLT3G | SOT-23 <br> (Pb-Free) | $10,000 /$ <br> Tape \& Reel |

$\dagger$ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## MMBZxxVxL, SZMMBZxxVxL Series

## MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
| :---: | :---: | :---: | :---: |
| Peak Power Dissipation @ 1.0 ms (Note 1) @ $\mathrm{T}_{\mathrm{L}} \leq 25^{\circ} \mathrm{C}$ | $\mathrm{P}_{\mathrm{pk}}$ | 40 | Watts |
| Total Power Dissipation on FR-5 Board (Note 2) @ $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ Derate above $25^{\circ} \mathrm{C}$ | $P_{\text {D }}$ | $\begin{gathered} 225 \\ 1.8 \end{gathered}$ | $\underset{\mathrm{mW} /{ }^{\circ} \mathrm{C}}{\mathrm{~mW}}$ |
| Thermal Resistance Junction-to-Ambient | $\mathrm{R}_{\text {өJA }}$ | 556 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Total Power Dissipation on Alumina Substrate (Note 3) @ $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ Derate above $25^{\circ} \mathrm{C}$ | $\mathrm{P}_{\mathrm{D}}$ | $\begin{gathered} 300 \\ 2.4 \end{gathered}$ | $\underset{\mathrm{mW} /{ }^{\circ} \mathrm{C}}{\mathrm{~mW}}$ |
| Thermal Resistance Junction-to-Ambient | $\mathrm{R}_{\text {өJA }}$ | 417 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Junction and Storage Temperature Range | $\mathrm{T}_{\mathrm{J}}, \mathrm{T}_{\text {stg }}$ | -55 to +150 | ${ }^{\circ} \mathrm{C}$ |
| Lead Solder Temperature - Maximum (10 Second Duration) | $\mathrm{T}_{\mathrm{L}}$ | 260 | ${ }^{\circ} \mathrm{C}$ |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Nonrepetitive current pulse per Figure 5 and derate above $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ per Figure 6 .
2. $\mathrm{FR}-5=1.0 \times 0.75 \times 0.62 \mathrm{in}$.
3. Alumina $=0.4 \times 0.3 \times 0.024$ in., $99.5 \%$ alumina

## ELECTRICAL CHARACTERISTICS

( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise noted)
UNIDIRECTIONAL (Circuit tied to Pins 1 and 3 or 2 and 3 )

| Symbol | Parameter |
| :---: | :--- |
| $\mathrm{I}_{\mathrm{PP}}$ | Maximum Reverse Peak Pulse Current |
| $\mathrm{V}_{\mathrm{C}}$ | Clamping Voltage @ $\mathrm{I}_{\mathrm{PP}}$ |
| $\mathrm{V}_{\mathrm{RWM}}$ | Working Peak Reverse Voltage |
| $\mathrm{I}_{\mathrm{R}}$ | Maximum Reverse Leakage Current $@ \mathrm{~V}_{\mathrm{RWM}}$ |
| $\mathrm{V}_{\mathrm{BR}}$ | Breakdown Voltage $@ \mathrm{I}_{\mathrm{T}}$ |
| $\mathrm{I}_{\mathrm{T}}$ | Test Current |
| $\mathrm{V}_{\mathrm{BR}}$ | Maximum Temperature Coefficient of $\mathrm{V}_{\mathrm{BR}}$ |
| $\mathrm{I}_{\mathrm{F}}$ | Forward Current |
| $\mathrm{V}_{\mathrm{F}}$ | Forward Voltage @ $\mathrm{I}_{\mathrm{F}}$ |



ELECTRICAL CHARACTERISTICS $\left(\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}\right.$ unless otherwise noted)
UNIDIRECTIONAL (Circuit tied to Pins 1 and 3 or Pins 2 and 3 )
$\left(V_{F}=0.9 \mathrm{~V}\right.$ Max @ $\left.\mathrm{I}_{\mathrm{F}}=10 \mathrm{~mA}\right)$

| Device* | Device Marking | $\mathrm{V}_{\text {RWM }}$ | $\mathrm{I}_{\mathrm{R}} @ \mathrm{~V}_{\mathrm{RWM}}$ | Breakdown Voltage |  |  |  | $\mathbf{V}_{\mathbf{C}}$ @ Ipp (Note 5) |  | $V_{\text {BR }}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | $\mathrm{V}_{\text {BR }}$ (Note 4) (V) |  |  | @ IT | $\mathrm{V}_{\mathrm{c}}$ | IPP |  |
|  |  | Volts | nA | Min | Nom | Max | mA | V | A | $\mathrm{mV} /{ }^{\circ} \mathrm{C}$ |
| MMBZ15VDLT1G/T3G | 15D | 12.8 | 100 | 14.3 | 15 | 15.8 | 1.0 | 21.2 | 1.9 | 12 |

( $\mathrm{V}_{\mathrm{F}}=1.1 \mathrm{~V} \operatorname{Max}$ @ $\mathrm{I}_{\mathrm{F}}=\mathbf{2 0 0} \mathrm{mA}$ )

| Device* | Device Marking | $\frac{V_{\text {RWM }}}{\text { Volts }}$ | $\frac{\mathrm{I}_{\mathrm{R}} @ \mathrm{~V}_{\mathrm{RWM}}}{\mathrm{nA}}$ | Breakdown Voltage |  |  |  | $\mathbf{V}_{\mathbf{C}}$ @ $\mathrm{IPP}^{\text {(Note 5) }}$ |  | $\mathrm{V}_{\text {BR }}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | $\mathrm{V}_{\text {BR }}$ (Note 4) (V) |  |  | @ $\mathbf{T}_{\mathbf{T}}$ | $\mathrm{V}_{\mathrm{C}}$ | IPP |  |
|  |  |  |  | Min | Nom | Max | mA | V | A | $\mathrm{mV} /{ }^{\circ} \mathrm{C}$ |
| MMBZ27VCLT1G/T3G | 27C | 22 | 50 | 25.65 | 27 | 28.35 | 1.0 | 38 | 1.0 | 26 |
| MMBZ39VCLT1G/T3G | 39C | 31.2 | 50 | 37.05 | 39 | 40.95 | 1.0 | 55 | 0.76 | 35.3 |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.
4. $V_{B R}$ measured at pulse test current $I_{T}$ at an ambient temperature of $25^{\circ} \mathrm{C}$.
5. Surge current waveform per Figure 5 and derate per Figure 6
*Include SZ-prefix devices where applicable.


Figure 1. Typical Breakdown Voltage versus Temperature


Figure 3. Typical Leakage Current versus Temperature


Figure 5. Pulse Waveform


Figure 2. Typical Breakdown Voltage versus Temperature


Figure 4. Steady State Power Derating Curve


Figure 6. Pulse Derating Curve

## MMBZxxVxL, SZMMBZxxVxL Series

TYPICAL APPLICATIONS
 central point near the DLC.

## Figure 7. Single Wire CAN Network

Figure is the recommended solution for transient EMI/ESD protection. This circuit is shown in the Society of Automotive Engineers February, 2000 J2411 "Single Wire CAN Network for Vehicle Applications" specification (Figure 6, page 11). Note: the dual common anode zener configuration shown above is electrically equivalent to a dual common cathode zener configuration.


SOT-23 (TO-236)
CASE 318-08
ISSUE AS
DATE 30 JAN 2018

## SCALE 4:1



NOTES:
IMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994
. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

|  | MILLIMETERS |  |  | INCHES |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| DIM | MIN | NOM | MAX | MIN | NOM | MAX |
| A | 0.89 | 1.00 | 1.11 | 0.035 | 0.039 | 0.044 |
| A1 | 0.01 | 0.06 | 0.10 | 0.000 | 0.002 | 0.004 |
| b | 0.37 | 0.44 | 0.50 | 0.015 | 0.017 | 0.020 |
| $\mathbf{c}$ | 0.08 | 0.14 | 0.20 | 0.003 | 0.006 | 0.008 |
| D | 2.80 | 2.90 | 3.04 | 0.110 | 0.114 | 0.120 |
| E | 1.20 | 1.30 | 1.40 | 0.047 | 0.051 | 0.055 |
| e | 1.78 | 1.90 | 2.04 | 0.070 | 0.075 | 0.080 |
| L | 0.30 | 0.43 | 0.55 | 0.012 | 0.017 | 0.022 |
| L1 | 0.35 | 0.54 | 0.69 | 0.014 | 0.021 | 0.027 |
| $\mathbf{H E}_{\mathbf{E}}$ | 2.10 | 2.40 | 2.64 | 0.083 | 0.094 | 0.104 |
| T | $0^{\circ}$ | --- | $10^{\circ}$ | $0^{\circ}$ | --- | $10^{\circ}$ |

GENERIC
MARKING DIAGRAM*

RECOMMENDED SOLDERING FOOTPRINT


DIMENSIONS: MILLIMETERS


XXX = Specific Device Code
M = Date Code

- = Pb-Free Package
*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " $\quad$ ", may or may not be present.


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1N4760ARL 1N5221B 1N5236B 1N5241BTR 1N5242BTR 1N5350B 1N5352B 1N961BRR1 1N964BRL RKZ5.1BKU\#P6
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